NSN 5961-00-814-9086

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A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-814-9086 **Inclosure Material:** Metal **Overall Length:** 0.700 inches **Overall Diameter:** 0.350 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -110.0 breakdown voltage, collector-to-base, emitter open and -110.0 breakdown voltage, collector-to-emitter, base open and -110.0 breakdown voltage, emitter-to-base, collector open **Maximum Operating Tempurature Per Measurement Point:** 160.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: